

Evidence for a universal length scale of dynamic charge inhomogeneity in cuprate superconductors

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Time-resolved optical experiments can give unique information on the characteristic length scales of dynamic charge inhomogeneity on femtosecond timescales. From data on the effective quasiparticle relaxation time τ_r in $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ and $\text{Nd}_{2-x}\text{Ce}_x\text{CuO}_4$ we derive the temperature- and doping- dependence of the intrinsic phonon escape length l_e , which, under certain circumstances, can be shown to be a direct measure of charge inhomogeneity. Remarkably, a common feature of both p and n -type cuprates - which has important consequences for superconductivity - is that as $T \rightarrow T_c$ from above, the escape length approaches the zero-temperature superconducting coherence length, $l_e \rightarrow \xi_s(0)$. In close vicinity of T_c , l_e appears to follow the critical behaviour of the Ginsburg-Landau coherence length, $\xi_{\text{GL}}(T)$. In the normal state l_e is found to be in excellent agreement with the mean free path l_m obtained from the resistivity data. The data on l_e also agree well with the data on structural coherence lengths l_s obtained from neutron scattering experiments, implying the existence of complex intrinsic textures on different length scales which may have a profound effect on the functional properties of these materials.

In recent years, substantial experimental evidence has started to accumulate for the existence of inhomogeneity in cuprates and other functional oxides, suggesting that it plays a fundamental role in their physics. Unfortunately, *dynamic* inhomogeneity – which is particularly important – is not easily and unambiguously detectable¹ since many standard techniques for investigating electronic and lattice structure fail when it comes to detecting dynamically changing deviations from the average structure. The current evidence for dynamic structural inhomogeneity comes from XAFS² and neutron PDF³ experiments, which have sufficiently short intrinsic experimental timescales to give information on dynamical local structure fluctuations, but unfortunately have a limited range of – at most – a few lattice constants⁴. Some other experiments, such as inelastic neutron scattering^{5,6,7} and scanning tunnelling microscopy⁸ have suggested a characteristic length scale of the inhomogeneity of the order of 1-2 nanometers, but no information on the dynamics can be deduced from these experiments.

In this report, we present new femtosecond-timescale information on charge inhomogeneity as a function of temperature and doping in selected cuprate superconductors. Using time-resolved optical experiments we extract the characteristic length scale l_c of charge inhomogeneities from the effective quasiparticle lifetime τ_r , and compare these results to data obtained from other established techniques.

We find remarkable agreement of the dynamical length scale measured by time-resolved spectroscopy with structural coherence lengths l_s determined from inelastic diffuse neutron scattering as well as the normal state mean free path l_m obtained from conductivity measurements over a wide range of temperatures.

To understand how we can derive a length scale from time-resolved measurements of the quasiparticle lifetimes, let us first consider the dynamics of the creation of bound states such as Cooper pairs (or charged stripes) from unbound particles. The formation of a bound state from unbound Fermions leads to the release of energy 2Δ in the form of a phonon (there is no other excitation which can remove the energy from the electronic subsystem). However, as was pointed out by Rothwarf and Taylor (R-T) already in 1967⁹, unless the phonon lifetime is zero, the emitted phonon can be efficiently reabsorbed again, breaking pairs, and leading to the formation of a relaxation bottleneck. The overall kinetics of pairing are typically described by the R-T rate equations for the quasiparticle density n , and the optical phonon density N respectively as $\frac{dn}{dt} = I_0 + \beta N - Rn^2$ and $\frac{dN}{dt} = -\frac{1}{2}(\beta N - Rn^2) - \gamma(N - N_T)$, where β is the pair-breaking rate by phonons with $\hbar\omega_{ph} > 2\Delta$, R is the recombination rate, N is the non-equilibrium density and N_T is the density of optical phonons in thermal equilibrium. γ is the rate at which optical phonons decay or escape by processes other than pair excitation. Under bottleneck conditions, $\beta N \approx Rn^2$, and the overall relaxation rate is dominated by the phonon escape term $\gamma(N - N_T)$. Thus, the experimentally observed relaxation time τ_r is determined by the escape of phonons from the recombination volume, rather than by the direct pair recombination rate R . In low- T_c superconductors which have a relatively small superconducting energy gap $2\Delta < 10$ meV, acoustic phonons are emitted by this process, and experiments on Al and Pb have clearly shown that the observed recombination time τ_r depends on superconducting film thickness, as predicted by the R-T model¹⁰.

In HTS superconductors, pre-formed pairs or other forms of bound states may form in the normal state ($T > T_c$), so R-T relaxation might be expected also above T_c , where it would

apply to the formation of bipolarons or stripes from unbound particles. First, high frequency optical phonons (with $\hbar\omega > 2\Delta$) are emitted, which subsequently decay anharmonically to acoustic phonons¹¹. However, these acoustic phonons can efficiently recombine again to excite optical phonons, which in turn break up pairs again until eventually the acoustic phonons disperse out of the recombination volume. By analogy with the R-T equations, the rate equations for the optical phonon decay to acoustic phonons and acoustic phonon escape can then be written as:

$$\frac{dN}{dt} = G_0 - \frac{1}{2}(\chi N - \delta M^2) \quad (1)$$

$$\frac{dM}{dt} = \chi N - \delta M^2 - \kappa(M - M_T) \quad (2)$$

Where G_0 is the optical phonon generation rate by QPs, M is the density of acoustic phonons, and $\kappa(M - M_T)$ describes the acoustic phonon escape, χ is the rate of optical phonon decay to acoustical phonons, while δ is the rate of acoustic phonon re-absorption. Under bottleneck conditions (i.e. near-steady-state) $\chi N \approx \delta M^2$, so using $\frac{dM}{dt} = v_s \frac{dM}{dr}$, Eq. (2) we obtain an explicit equation for the phonon escape:

$$\frac{dM}{dr} = -l_e^{-1}(M - M_T) \quad (3)$$

where $l_e = v_s/\kappa$ is the phonon escape length. The justification for the steady-state assumption can be tested through comparison with experiments. If it can be shown that l_e is determined by geometrical constraints, such as film thickness, as was done in conventional superconductors, then the steady-state assumption can be fully justified. Importantly, if the material is intrinsically inhomogeneous, the relevant geometrical constraints on the recombination volume are determined by the inhomogeneity length scale, and the relaxation time may be dominated by the phonons' escape from one phase

(charge-rich) into another (charge-poor), as shown schematically in the insert to Fig.1.

Inhomogeneities on the nanometer scale give rise to phonon escape times on the picosecond timescale, which is directly measurable with current ultrafast laser spectroscopy.

Over the past few years, several experiments have been carried out on cuprates to measure the temperature dependence of the relaxation time τ_r ^{11,12,13,14,15,16,17}. A typical data set showing the photoinduced normalized reflectivity as a function of time is shown in Figure 1 for $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$, at different temperatures for $x=0.1$. (The experimental details are described in ref. 18). From the fitted relaxation time τ_r , we can analyse the characteristic phonon escape lengths l_e as a function of T . We concentrate on $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) here, because the relevant data are most complete for this compound. Using measured values of τ_r ¹⁸ and v_s ¹⁹, in Figure 2 we have plotted l_e for $x = 0.06 - 0.2$, at different temperatures. For all superconducting samples ($x = 0.1-0.2$), l_e shows a gradual increase from approximately $l_e \approx 1$ nm at 300K to about $l_e \approx 2 - 3$ nm near T_c . Well below T_c , l_e continues to increase rapidly, but with a different slope. (The insulating sample on the other hand ($x=0.06$) shows almost no temperature dependence of l_e over this temperature range.)

Close to T_c , l_e shows signs of critical behaviour, exhibiting a clear peak. This peak is more pronounced in some materials than others^{11,12,13,18}, and depends on experimental conditions (such as incident laser power), but it is generally present only in a narrow 2-3K region near T_c . At a 2nd order phase transition (such as the superconducting transition), the correlation (coherence) length is expected to diverge as $\xi_s \sim (T_c - T)^{-\nu}$ above and as $\xi_s \sim (T - T_c)^{-\nu}$ below T_c . Plotting the critical region near T_c for $\text{La}_{1.9}\text{Sr}_{0.1}\text{CuO}_4$ in the

insert to Fig. 3, we see that the critical exponent of l_e is near $\nu=0.5$, the mean field theory value, and is consistent with the relation $l_e = v_s \tau_r \sim \Delta^{-1} \sim \xi_s^{-1/2}$ discussed previously¹³. The obvious implication from the data in Fig. 3a), that l_e is related to $\xi_s(T)$ in the vicinity of T_c is quite remarkable, and is far from trivial. Although the detailed theoretical justification for this statement is beyond the scope of this paper, we wish to remark here that the connection between $\xi_s(T)$ and $l_e(T)$ implies that the charge inhomogeneity governs the behaviour of the superconducting phase coherence and the transition to the superconducting state at T_c ²⁰. The corollary is that the presence of inhomogeneity on a scale shorter than the coherence length clearly prevents the formation of a phase coherent superconducting state.

We can check if our understanding of the recombination dynamics in terms of inhomogeneity-limited phonon escape is appropriate, by comparing l_e with the length scales obtained from other experiments which can sense dynamic inhomogeneity. An obvious example is the mean free path l_m of charge carriers in the normal state, which can be obtained from DC resistivity measurements. Expressing l_m via the Drude formula in terms of the relevant experimentally measurable quantities such as the *ab*-plane superconducting penetration depth λ_s and Fermi velocity v_F (rather than effective mass and density), we obtain $l_m = \frac{\lambda_s^2 v_F}{\epsilon_0 c^2} \sigma(T)$, where $\sigma(T)$ is the normal state conductivity. In Figure 3a) we show a comparison between l_e and l_m (normalised to the superconducting coherence length ξ_s) using measured values of λ_s ²¹, v_F ²² and in-plane $\sigma(T)$ ²³ for $x = 0.1$ and $x = 0.15$ as a function of T/T_c . We observe remarkable quantitative agreement between l_e and l_m over the entire temperature range ($T_c < T < 300\text{K}$) where the data sets

overlap. The implication is that the charged carrier mean free path l_m and the phonon escape length l_e , are both being determined by the same underlying texture, and

$$\text{empirically, } \frac{\sigma(T)}{\tau_r(T)} \approx \frac{\epsilon_0 c^2 v_s}{\lambda_s^2 v_F}.$$

To determine if the underlying length scale is connected with *structural* inhomogeneity, we compare l_m and l_e with the *structural* coherence length l_s determined by neutron scattering experiments on LSCO. The latter is defined as the length scale over which a particular structure which gives rise to the diffraction peak is coherent⁷. Although we are not aware of any detailed studies of structural inhomogeneities over a large range of temperatures, Kimura et al⁷ deduced a structural coherence length of $l_s = 1/\Delta k \sim 1.7$ nm in slightly underdoped $\text{La}_{1.88}\text{Sr}_{0.12}\text{CuO}_4$ around 315 K from the linewidth of the diffuse central peak ($\Delta k = 0.06 \text{ \AA}^{-1}$) in neutron scattering. Well below T_c (at $T = 13.5$ K), this structural coherence length is apparently extended to $l_s > 10$ nm⁷. Inelastic neutron scattering experiments on phonons in LSCO also show an anomaly with a characteristic wavevector $k_0 \sim \pi/2a$ (where a is the lattice constant), corresponding to a length scale of the underlying textures of $l \approx 2$ nm⁵. Comparing these values with l_e and l_m in Fig. 3a), albeit for the limited data that exist, we see impressive agreement, suggesting that the structural coherence length l_s corresponds closely with the characteristic electronic inhomogeneity length scale l_e .

An interesting question is whether the behaviour $l_e \rightarrow \xi_s(0)$, as $T \rightarrow T_c$ is evident also for *n*-type materials such as $\text{Nd}_{2-x}\text{Ce}_x\text{CuO}_4$ (NCCO)¹⁴, even though $\xi_s(0)$ is approximately an order of magnitude larger than in *p*-type cuprate²⁹. In Figure 3b) we compare the normalised phonon escape length $l_e/\xi_s(0)$ vs. T/T_c for optimally doped LSCO and NCCO

(both $x = 0.15$). Remarkably, the normalized $l_e/\xi_s(0)$ is very similar for NCCO and LSCO over a substantial temperature range near, and above T_c .

In contrast to the behaviour above and near T_c , the T -dependence of l_e *well below* T_c does not appear to be universal. For example τ_r (and hence also l_e) has previously been suggested to follow power law behaviour of the form $\tau_r \sim T^{-\eta}$ with $\eta=3$ below T_c in LSCO¹⁵, but this is apparently not always the case, as we can see from Figure 3.

Expressing the escape length as $l_e/\xi_s(0) = (T/T_c)^{-\eta}$, in Fig. 3b) we observe very different behaviour for LSCO for NCCO, with $\eta \approx 2$ and $\eta \approx 0$ respectively. Furthermore, examination of data for τ_r on $\text{YBa}_2\text{Cu}_3\text{O}_{7.8}$ ¹², $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_8$ ¹² and $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_8$ ¹⁶ also reveals quite diverse behaviour below T_c , which might be an indication that the typical T -dependence of l_e might not be intrinsic, but is determined by characteristic lattice defect textures or impurities. In fact, the T -dependence of τ_r in high quality underdoped single crystals of $\text{YBa}_2\text{Cu}_3\text{O}_{6.5}$ ²⁴ show markedly different T -dependence than in quenched thin film samples (presumably with quenched O disorder)^{11,12}, the former showing much longer relaxation times (and whence longer l_e) below T_c , highlighting the importance of disorder, domains and defects, which are all likely to have a profound influence on charge inhomogeneity. Indeed, well below T_c , as the relaxation time τ_r increases, competing relaxation processes may become operative. Unfortunately without comparisons with other experimental data of inhomogeneity length scales below T_c , we cannot empirically justify the steady-state assumption in Eqs. (1) and (2) as we did for $T \geq T_c$, and we presently refrain from further analysis of τ_r only in terms of Eq.(3) well below T_c until further data become available.

Although we have concentrated here on LSCO, from published data for τ_r and $\sigma(T)$ for $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ ¹², $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_8$ ¹² and $\text{HgBa}_2\text{Ca}_2\text{Cu}_3\text{O}_8$ ¹⁶ and comparison of l_e , l_m and l_s we can deduce that qualitatively, the behaviour is common, particularly (i) $l_e(T) \approx \xi_s(0)$ above T_c (but below T^*) and (ii) the divergence of $l_e(T)$ around T_c .

In the interest of brevity, in this paper we have oversimplified on a number of issues. For instance, we have not discussed the anisotropy of l_e . Moreover, the use of the simple Drude model is justified mainly by the fact that l_m and l_e agree so well, and we have not discussed the underlying origins of its T -dependence. This has been discussed elsewhere²⁵, as was the effect of superconducting gap anisotropy on the relaxation time τ_r ^{11,13}. In spite of this, the present analysis makes it clear that the physical properties of cuprates may be expected to be dominated by inhomogeneity, with different length scales at different T and x .

To conclude, we suggest a physical picture which can lead to the observed behaviour of l_e . Doped holes are unbound at high temperature, but at some temperature T^* - associated with the energy scale $kT^* \sim 2\Delta$, where Δ is the binding energy per particle - they start to form bound bipolaron pairs, leading to a charge-inhomogeneous state. Bipolarons form and dissociate according to thermal fluctuations, leading to a state which is dynamically inhomogeneous. The dimensions of these objects is determined by the balance of Coulomb repulsion and lattice attraction, as discussed in ref.[26] for example, and is of the order of the coherence length, $l = 1-2$ nm above T_c . As the temperature is reduced and the density of pairs increases, these pairs start to coalesce into larger objects, which is reflected by the longer length scale l_e at low temperatures²⁷. When some critical temperature T_c , the characteristic length-scale becomes comparable to the

superconducting coherence length $l(T) \approx \xi_{GL}(T)$, the percolation threshold is reached, and a macroscopically phase-coherent state is established ²⁰.

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Figure 1. The photoinduced reflectivity $\Delta R/R$ measured on $\text{La}_{1.9}\text{Sr}_{0.1}\text{CuO}_4$ as a function of time for different T . The relaxation is described reasonably well by a single exponential. Insert: a schematic representation of the phonon escape process arising from the pairing of two particles with E_1, k_1 and E_2, k_2 (solid lines) with the emission of acoustic phonons (wavy line) in an inhomogeneous medium. The overall rate of recombination is dominated by phonon escape out of the charged volume V .

Figure 2. The phonon escape length l_e as a function of temperature for $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ for $x=0.06, 0.1, 0.115, 0.15$ and 0.2 respectively. The T_c are $0, 31, 32, 38.5$ and 30 K respectively. ($x=0.06$ is non-superconducting.) Here we have used $v_s = 4.8 \text{ nm ps}^{-1}$ for LSCO for all x ¹⁹.

Figure 3 a). A plot of l_e (filled color symbols), l_m (open symbols) and l_s (black symbols) as a function of T/T_c for LSCO at different doping levels. In all cases the length scale is normalized to $\xi_s(0)$ ²⁸. The insert shows the critical behaviour just above T_c for $x=0.1$. The mean-field prediction is plotted $l/\xi_{GL}(T) \sim (T-T_c)^{-\nu}$, with

$v=1/2$ as a dashed line. b) The normalized escape lengths $l_e/\xi_s(0)$ for $\text{La}_{1.85}\text{Sr}_{0.15}\text{CuO}_4$ (filled squares) and $\text{Nd}_{1.85}\text{Ce}_{0.15}\text{CuO}_4$ (open circles) as a function of T/T_c . Here $\xi_s(0) = 1.8$ and 18 nm respectively for LSCO and NCCO²⁹. $v_s = 5.5 \text{ nm ps}^{-1}$ for NCCO³⁰.

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Fig.1

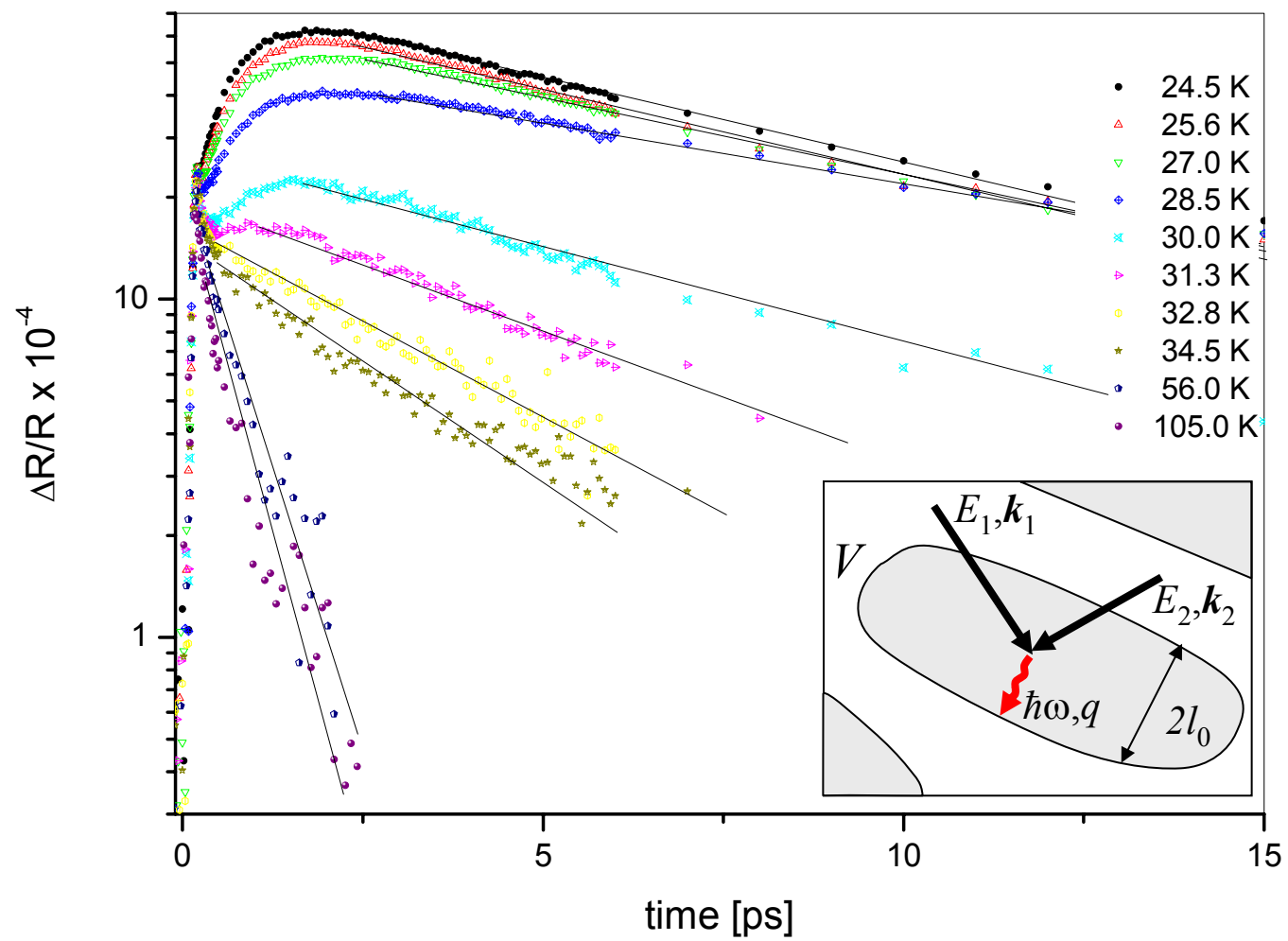


Fig. 2

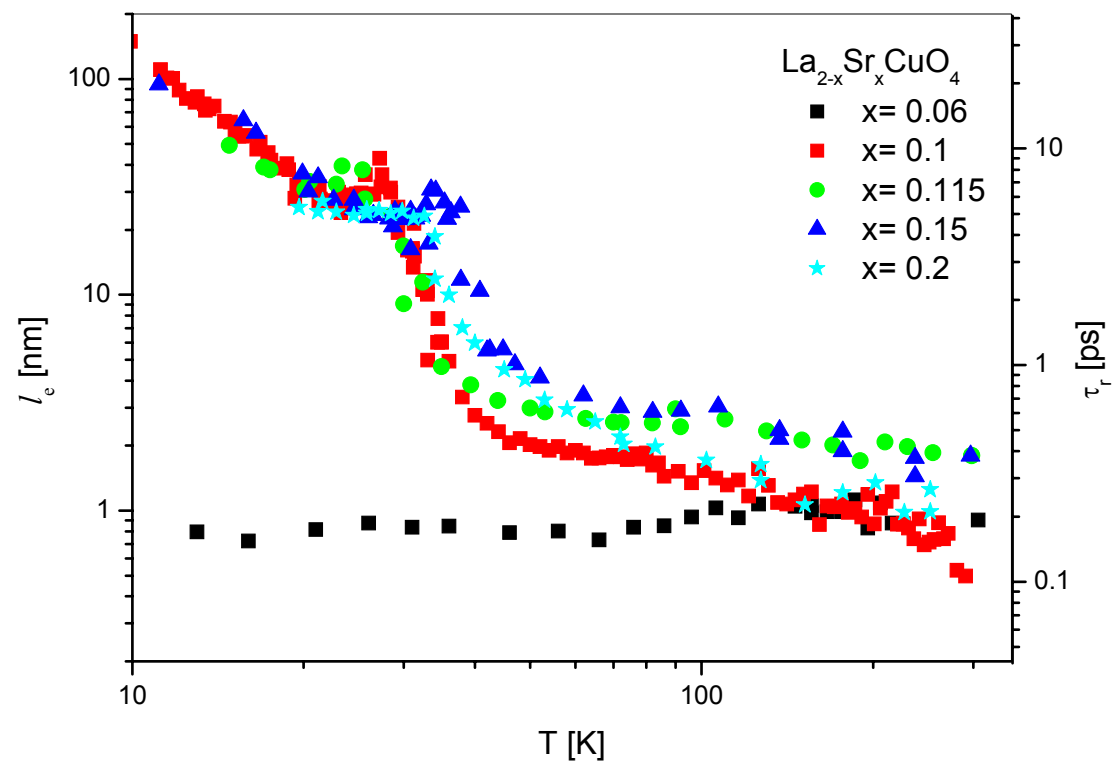


Fig. 3a)

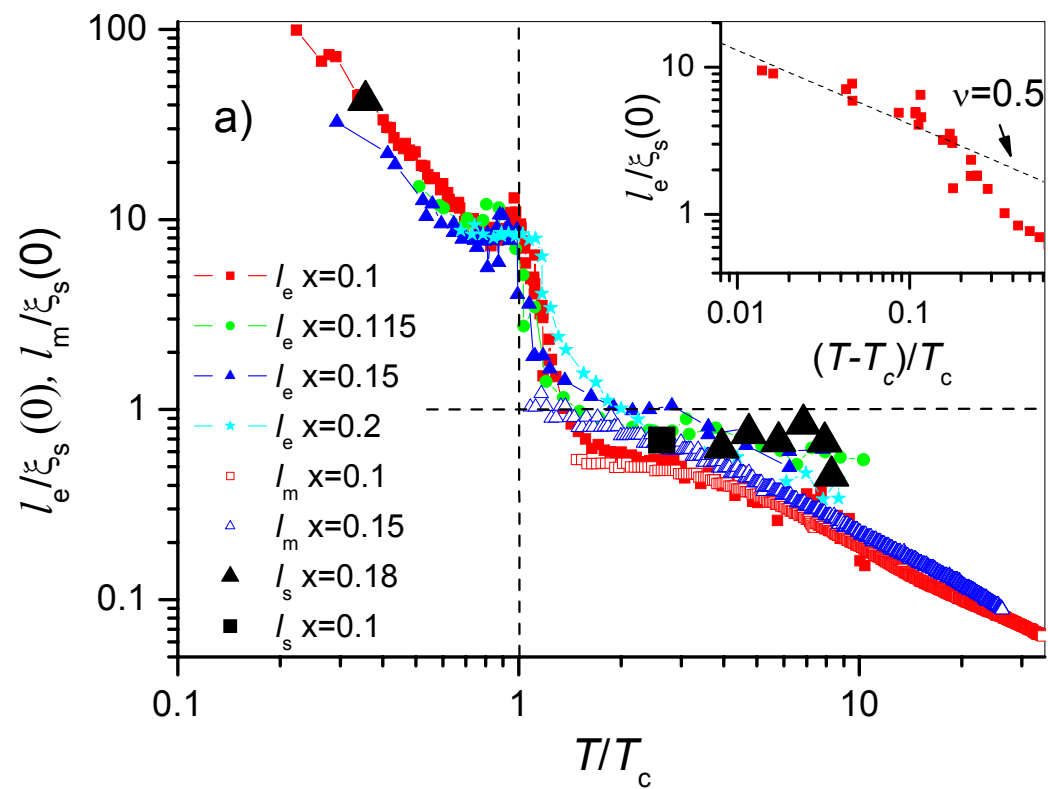


Fig. 3b)

